

# **BCR5AM-12LB**

# Triac

Medium Power Use

(The product guaranteed maximum junction temperature of 150°C)

REJ03G0452-0300 Rev.3.00 Nov 30, 2007

#### **Features**

 $I_{T(RMS)}: 5 A$ 

 $V_{DRM} : 600 \text{ V}$ 

 $I_{FGT I}$ ,  $I_{RGT I}$ ,  $I_{RGT III}$ : 20 mA (10 mA)<sup>Note6</sup>

Non-Insulated Type

Planar Passivation Type

#### **Outline**

RENESAS Package code: PRSS0004AA-A (Package name: TO-220)





- 1. T<sub>1</sub> Terminal
- 2. T<sub>2</sub> Terminal
- 3. Gate Terminal
- 4. T<sub>2</sub> Terminal

## **Applications**

Switching mode power supply, light dimmer, electronic flasher unit, control of household equipment such as TV sets, stereo systems, refrigerator, washing machine, infrared kotatsu, carpet, solenoid driver, small motor control, copying machine, electric tool, electric heater control, and other general purpose control applications

# Warning

- 1. Refer to the recommended circuit values around the triac before using.
- 2. Be sure to exchange the specification before using. Otherwise, general triacs with the maximum junction temperature of 125°C will be supplied.

### **Maximum Ratings**

Parameter	Symbol	Voltage class	Unit	
Farameter	Syllibol	12		
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	600	V	
Non-repetitive peak off-state voltage <sup>Note1</sup>	$V_{DSM}$	720	V	

## BCR5AM-12LB (The product guaranteed maximum junction temperature of 150°C)

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I <sub>T(RMS)</sub>	5	А	Commercial frequency, sine full wave 360° conduction, Tc = 128°C <sup>Note3</sup>
Surge on-state current	I <sub>TSM</sub>	50	А	60Hz sinewave 1 full cycle, peak value, non-repetitive
I <sup>2</sup> t for fusing	l <sup>2</sup> t	10.4	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	3	W	
Average gate power dissipation	$P_{G(AV)}$	0.3	W	
Peak gate voltage	$V_{GM}$	10	V	
Peak gate current	I <sub>GM</sub>	2	Α	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	
Mass	_	2.0	g	Typical value

Notes: 1. Gate open.

### **Electrical Characteristics**

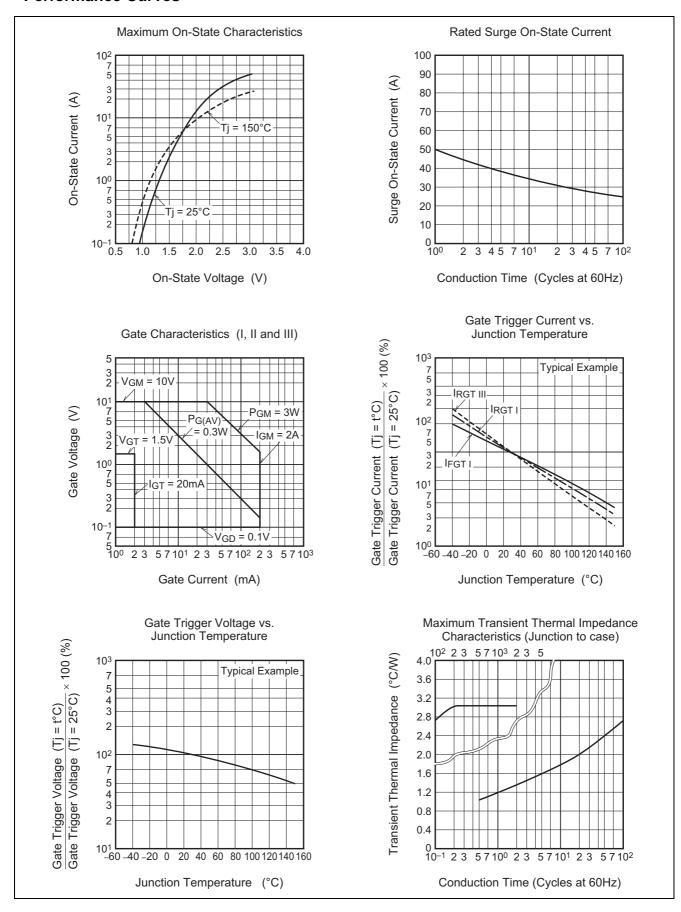
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I <sub>DRM</sub>	_	_	2.0	mA	Tj = 150°C, V <sub>DRM</sub> applied
On-state voltage		$V_{TM}$	_	_	1.8	V	$Tc = 25^{\circ}C, I_{TM} = 7 A,$
							Instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	I	$V_{FGT\ I}$	_		1.5	V	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	$V_{RGT\mathrm{I}}$	_		1.5	>	$R_G = 330 \Omega$
	III	$V_{RGTIII}$	_		1.5	>	
Gate trigger current <sup>Note2</sup>	I	I <sub>FGT I</sub>	_		20 <sup>Note6</sup>	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	I <sub>RGT I</sub>	_		20 <sup>Note6</sup>	mA	$R_G = 330 \Omega$
	III	I <sub>RGT III</sub>	_		20 <sup>Note6</sup>	mA	
Gate non-trigger voltage		$V_{GD}$	0.2/0.1	_	_	V	Tj = 125°C/150°C,
							$V_D = 1/2 V_{DRM}$
Thermal resistance		R <sub>th(j-c)</sub>	_	_	3.0	°C/W	Junction to case <sup>Note3 Note4</sup>
Critical-rate of rise of off-state commutating voltage <sup>Note5</sup>		(dv/dt)c	5/1	_	_	V/µs	Tj = 125°C/150°C

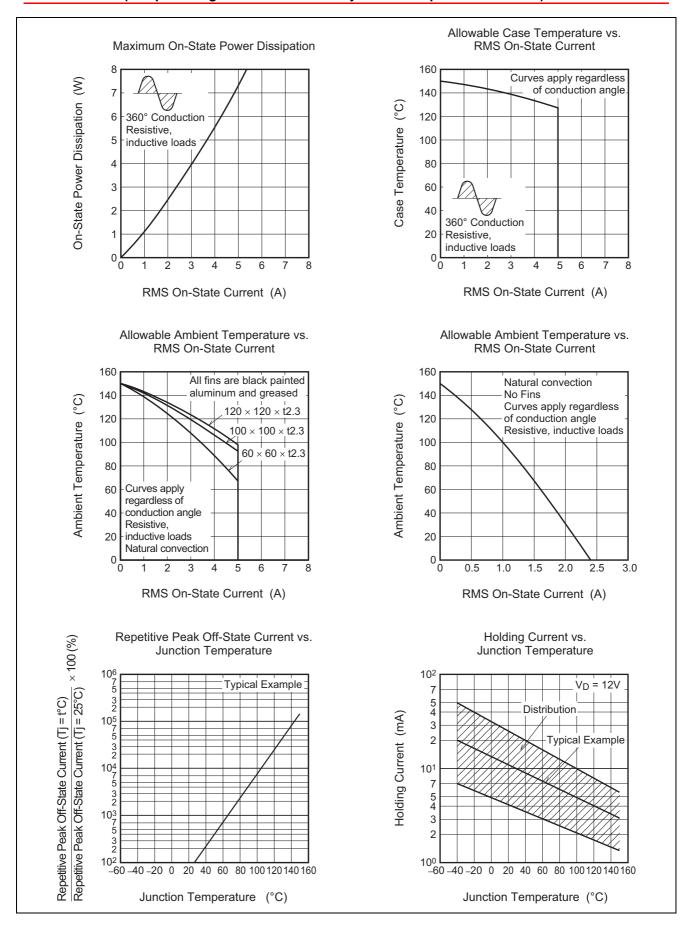
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

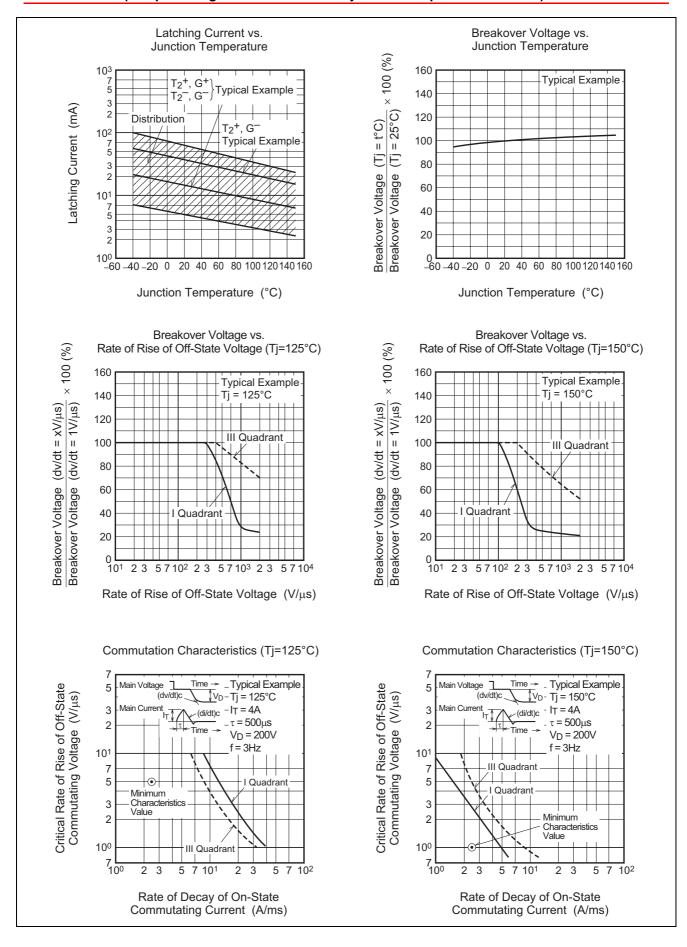
- 3. Case temperature is measured at the  $T_2$  tab 1.5 mm away from the molded case.
- 4. The contact thermal resistance  $R_{th\ (c\text{-}f)}$  in case of greasing is 1.0°C/W.
- 5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.
- 6. High sensitivity ( $I_{GT} \le 10 \text{ mA}$ ) is also available. ( $I_{GT}$  item: 1)

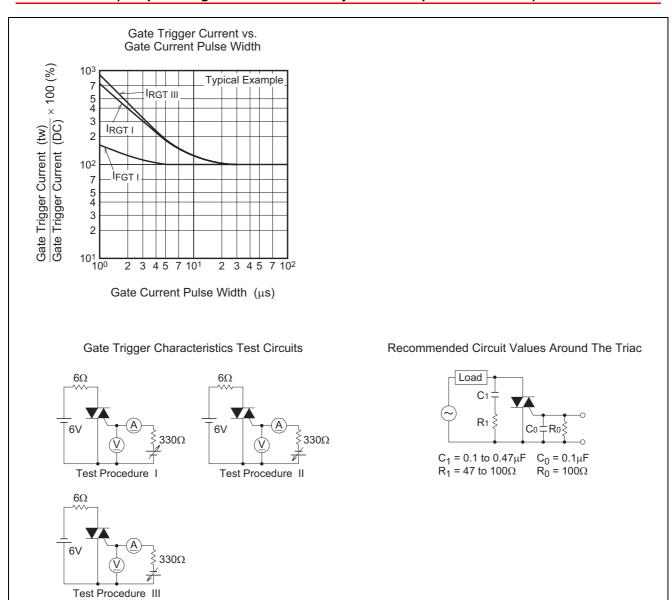
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125°C/150°C	Supply Voltage
<ul> <li>2. Rate of decay of on-state commutating current (di/dt)c = -2.5 A/ms</li> <li>3. Peak off-state voltage V<sub>D</sub> = 400 V</li> </ul>	Main Current  Main Voltage  (dv/dt)c  Time  VD

#### **Performance Curves**

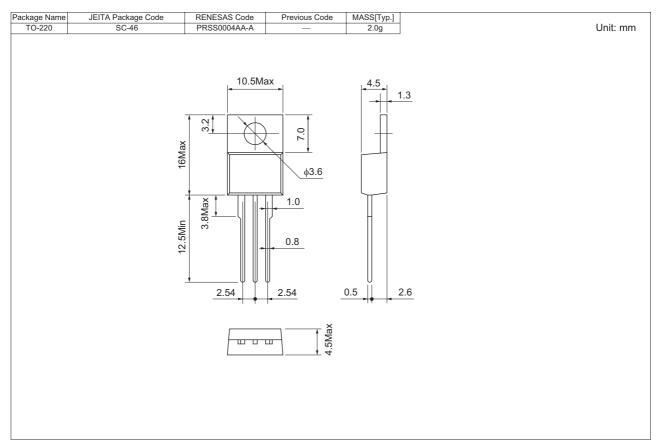








# **Package Dimensions**



# **Order Code**

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	100	Type name	BCR5AM-12LB
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	BCR5AM-12LB-A8

Note: Please confirm the specification about the shipping in detail.

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